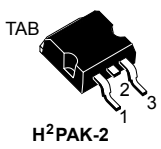
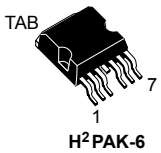
STH315N10F7-2, STH315N10F7-6

Datasheet

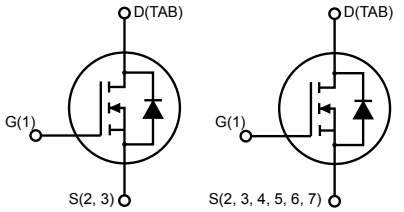
Automotive-grade N-channel 100 V, 2.1 mΩ typ., 180 A STripFET F7 Power MOSFETs in an H²PAK-2 and H²PAK-6 packages



H²PAK-2



H²PAK-6



for H²PAK-2

for H²PAK-6

N-CHG1DTABS23_2_6

Features

Order code	V_{DS}	$R_{DS(on)}$ max.	I_D
STH315N10F7-2	100 V	2.3 mΩ	180 A
STH315N10F7-6			

- AEC-Q101 qualified
- Among the lowest $R_{DS(on)}$ on the market
- Excellent FoM (figure of merit)
- Low C_{rss}/C_{iss} ratio for EMI immunity
- High avalanche ruggedness

Applications

- Switching applications

Description

These N-channel Power MOSFETs utilize STripFET F7 technology with an enhanced trench gate structure that results in very low on-state resistance, while also reducing internal capacitance and gate charge for faster and more efficient switching.

Product status
STH315N10F7-2
STH315N10F7-6

Product summary	
Order code	**STH315N10F7-2**
Marking	315N10F7
Package	H²PAK-2
Packing	Tape and reel
Order code	**STH315N10F7-6**
Marking	315N10F7
Package	H²PAK-6
Packing	Tape and reel

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1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage	100	V
V_{GS}	Gate-source voltage	±20	V
I_D (1)	Drain current (continuous) at T_C = 25 °C	180	A
I_D (1)	Drain current (continuous) at T_c = 100 °C	180	A
I_{DM} (2)	Drain current (pulsed)	720	A
P_{TOT}	Total dissipation at T_C = 25 °C	315	W
	Derating factor	2.1	W/°C
E_{AS} (3)	Single pulse avalanche energy	1	J
T_j	Operating junction temperature range	-55 to 175	°C
T_{stg}	Storage temperature range		

1. *Current limited by package.*
2. *Pulse width limited by safe operating area.*
3. *Starting T_j=25 °C, I_D=60 A, V_{DD}=50 V*

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance, junction-to-case	0.48	°C/W
R_{thJB} (1)	Thermal resistance, junction-to-board	35	°C/W

1. *When mounted on 1 inch² FR-4, 2 Oz copper board.*

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2 Electrical characteristics

(T_C = 25 °C unless otherwise specified)

Table 3. On/Off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	I_D = 250 µA, V_{GS} = 0 V	100			V
I_{DSS}	Zero gate voltage drain current	V_{GS} = 0 V, V_{DS} = 100 V			1	µA
		V_{GS} = 0 V, V_{DS} = 100 V, T_C=125 °C (1)			100	µA
I_{GSS}	Gate-body leakage current	V_{GS} = ±20 V, V_{DS} = 0 V			100	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS} = V_{GS} , I_D = 250 µA	2.5	3.5	4.5	V
$R_{DS(on)}$	Static drain-source on-resistance	V_{GS} = 10 V, I_D= 60 A		2.1	2.3	mΩ

1. *Defined by design, not subject to production test.*

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{iss}	Input capacitance	V_{DS} = 25 V, f = 1 MHz, V_{GS} = 0 V	-	12800	-	pF
C_{oss}	Output capacitance		-	3500	-	pF
C_{rss}	Reverse transfer capacitance		-	170	-	pF
Q_g	Total gate charge	V_{DD} = 50 V, I_D = 180 A, V_{GS} = 0 to 10 V (see Figure 13. Test circuit for gate charge behavior)	-	180	-	nC
Q_{gs}	Gate-source charge		-	78	-	nC
Q_{gd}	Gate-drain charge		-	34	-	nC

Table 5. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	V_{DD} = 50 V, I_D = 90 A, R_G = 4.7 Ω, V_{GS} = 10 V (see Figure 12. Test circuit for resistive load switching times and Figure 17. Switching time waveform)	-	62	-	ns
t_r	Rise time		-	108	-	ns
$t_{d(off)}$	Turn-off delay time		-	148	-	ns
t_f	Fall time		-	40	-	ns

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Table 6. Source-drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD}	Source-drain current		-		180	A
I_{SDM} (1)	Source-drain current (pulsed)		-		720	A
V_{SD} (2)	Source-drain curren	I_{SD} = 60 A, V_{GS} = 0 V	-		1.5	V
t_{rr}	Reverse recovery time	I_{SD} = 180 A, di/dt = 100 A/µs	-	85		ns
Q_{rr}	Reverse recovery charge	V_{DD} = 80 V, T_J = 150 °C (see Figure 14. Test circuit for inductive load switching and diode recovery times)	-	200		nC
I_{RRM}	Reverse recovery current		-	4.7		A

1. *Pulse width limited by safe operating area.*
2. *Pulsed: pulse duration=300 µs, duty cycle 1.5%.*

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2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

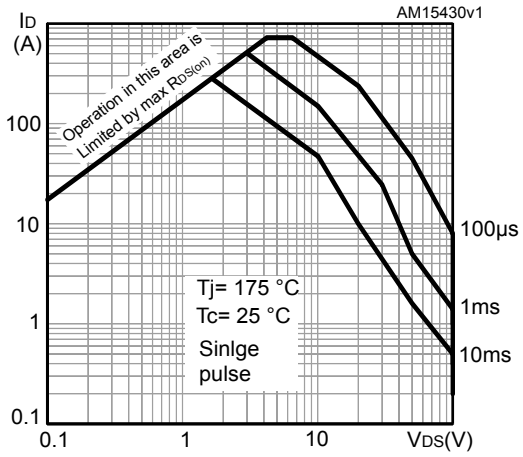


Figure 2. Thermal impedance

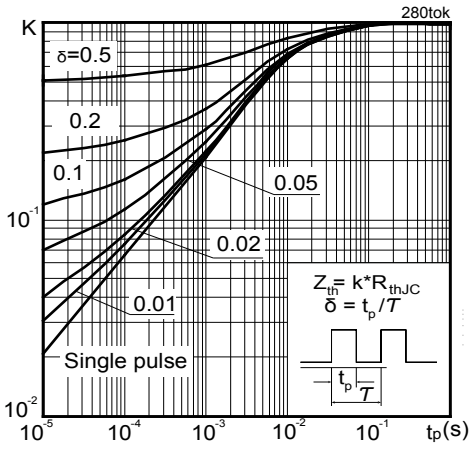


Figure 3. Output characteristics

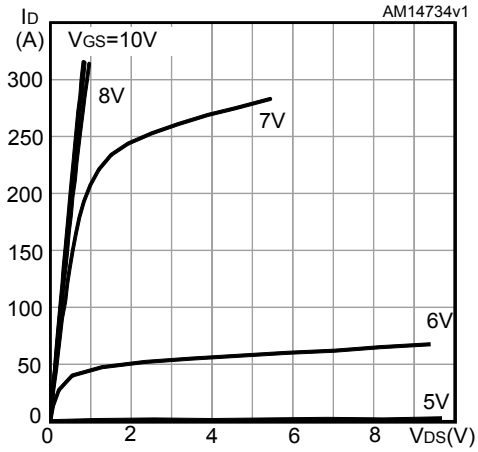


Figure 4. Transfer characteristics

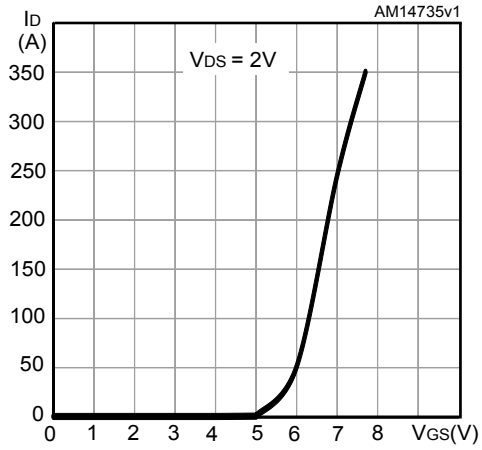


Figure 5. Gate charge vs gate-source voltage

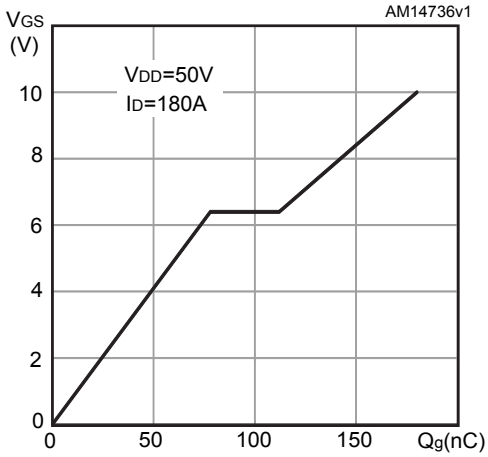
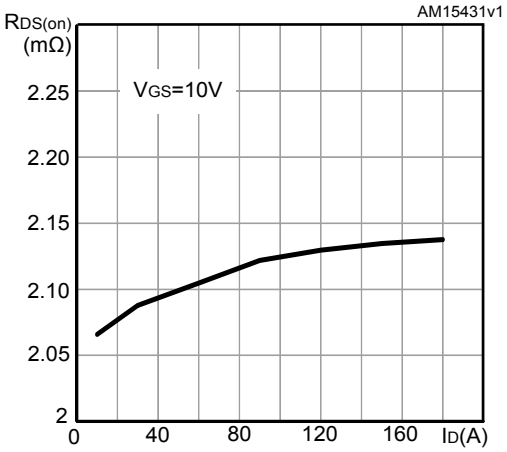


Figure 6. Static drain-source on-resistance



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Figure 7. Normalized $V_{(BR)DSS}$ vs temperature

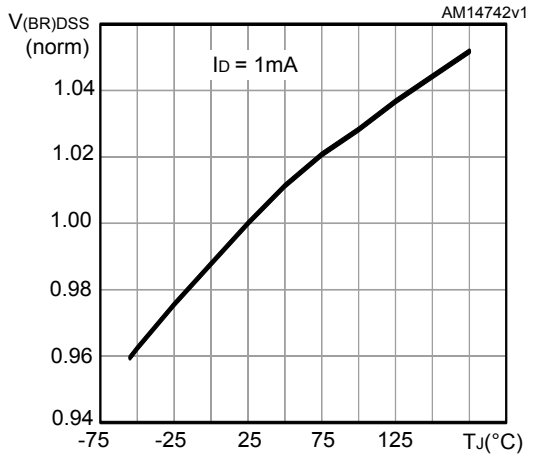


Figure 8. Capacitance variations

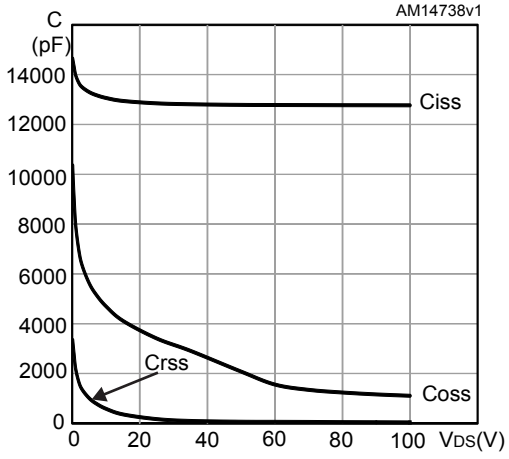


Figure 9. Source-drain diode forward characteristics

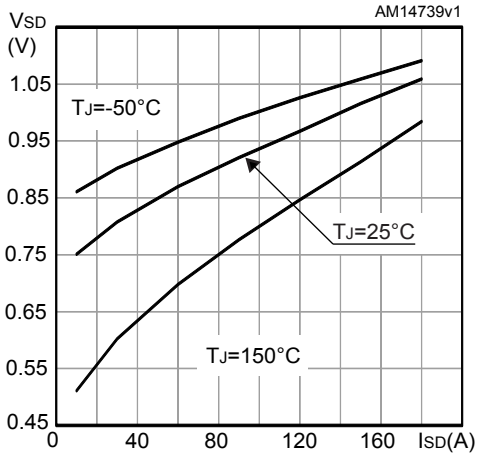


Figure 10. Normalized gate threshold voltage vs temperature

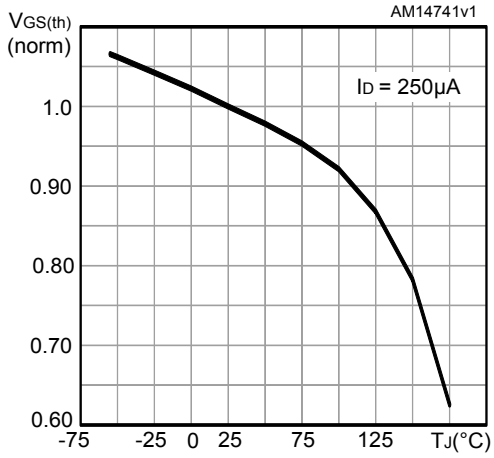
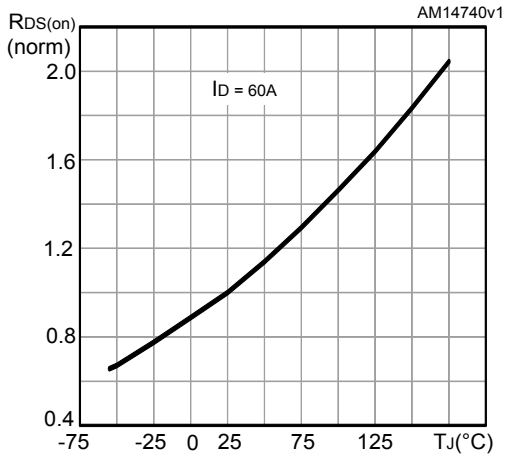


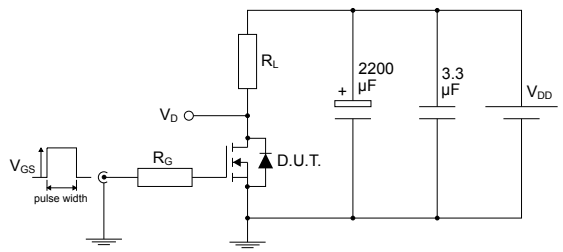
Figure 11. Normalized on-resistance vs temperature



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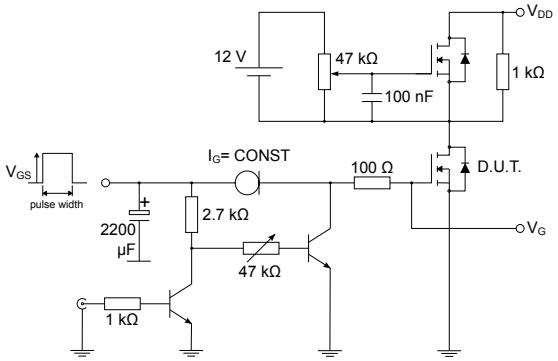
3 Test circuits

Figure 12. Test circuit for resistive load switching times



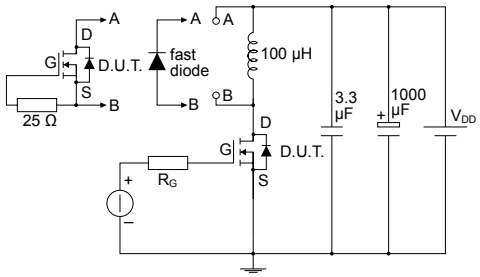
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Figure 13. Test circuit for gate charge behavior



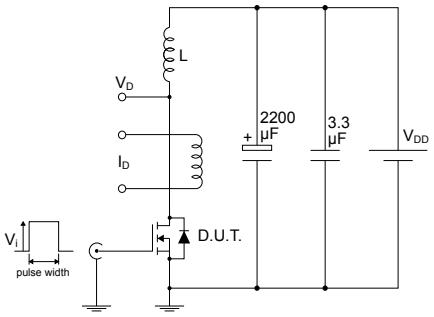
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Figure 14. Test circuit for inductive load switching and diode recovery times



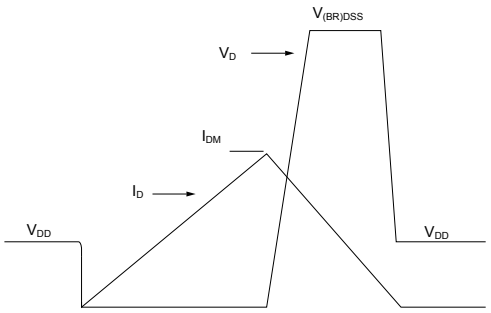
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Figure 15. Unclamped inductive load test circuit



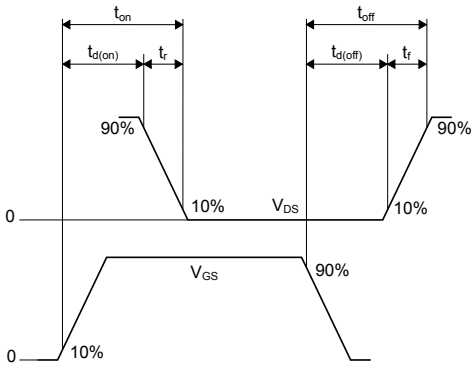
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Figure 16. Unclamped inductive waveform



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Figure 17. Switching time waveform



AM01473v1

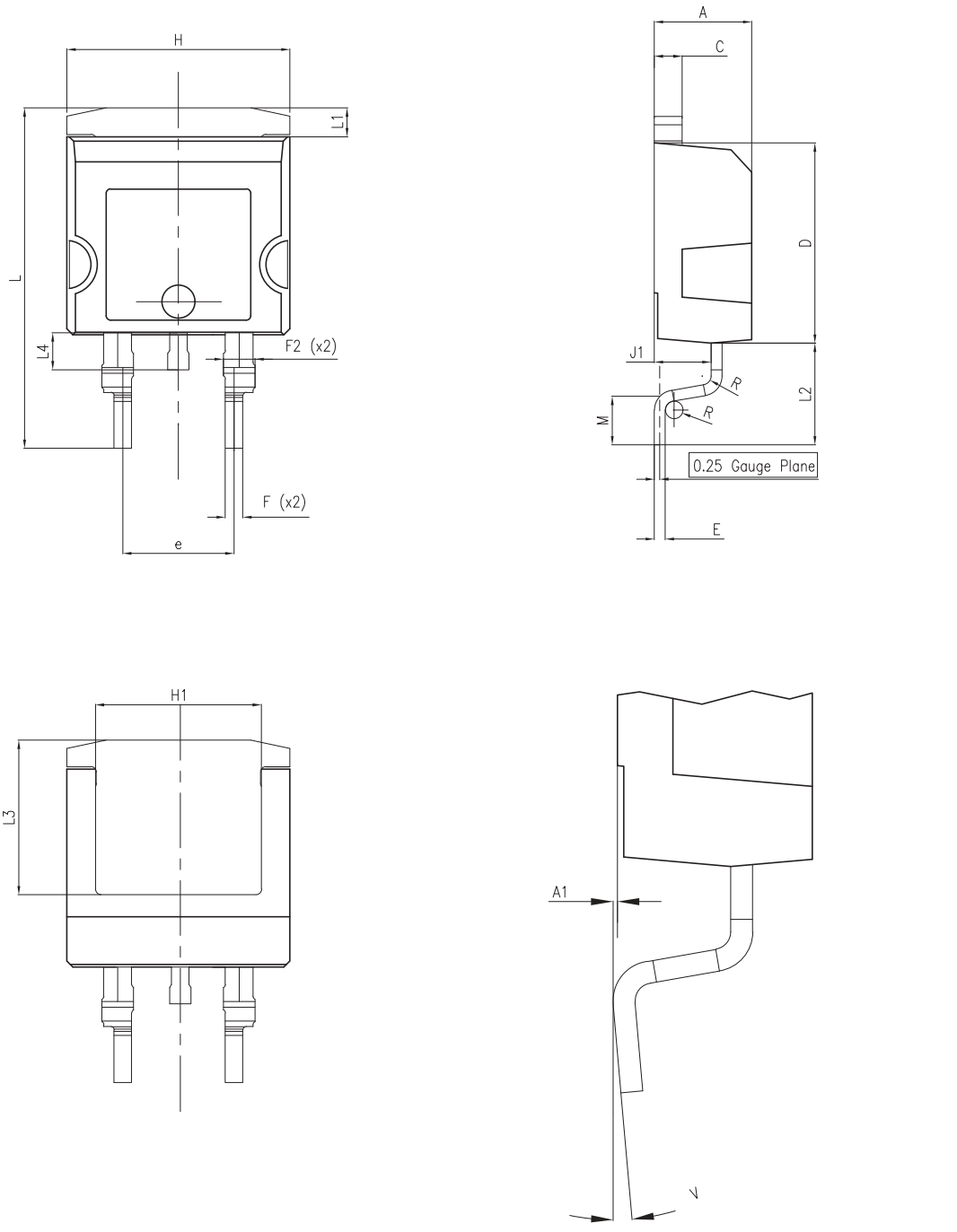
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4 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

4.1 H²PAK-2 package information

Figure 18. **H²PAK-2 package outline**

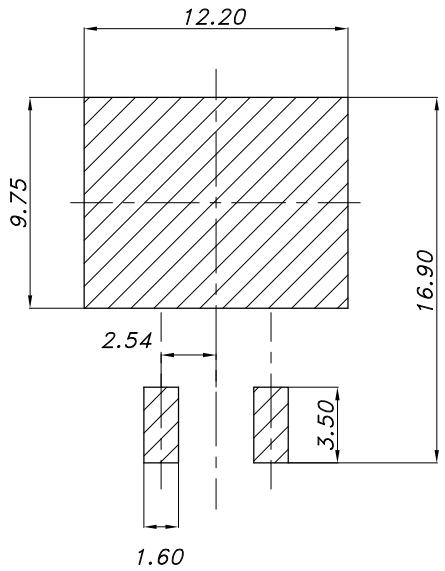


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Table 7. H²PAK-2 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.70
A1	0.03		0.20
C	1.17		1.37
D	8.95		9.35
e	4.98		5.18
E	0.50		0.90
F	0.78		0.85
F2	1.14		1.70
H	10.00		10.40
H1	7.40	-	7.80
J1	2.49		2.69
L	15.30		15.80
L1	1.27		1.40
L2	4.93		5.23
L3	6.85		7.25
L4	1.50		1.70
M	2.60		2.90
R	0.20		0.60
V	0°		8°

Figure 19. H²PAK-2 recommended footprint



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Note: Dimensions are in mm.

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4.2 H²PAK-6 package information

Figure 20. **H²PAK-6 package outline**

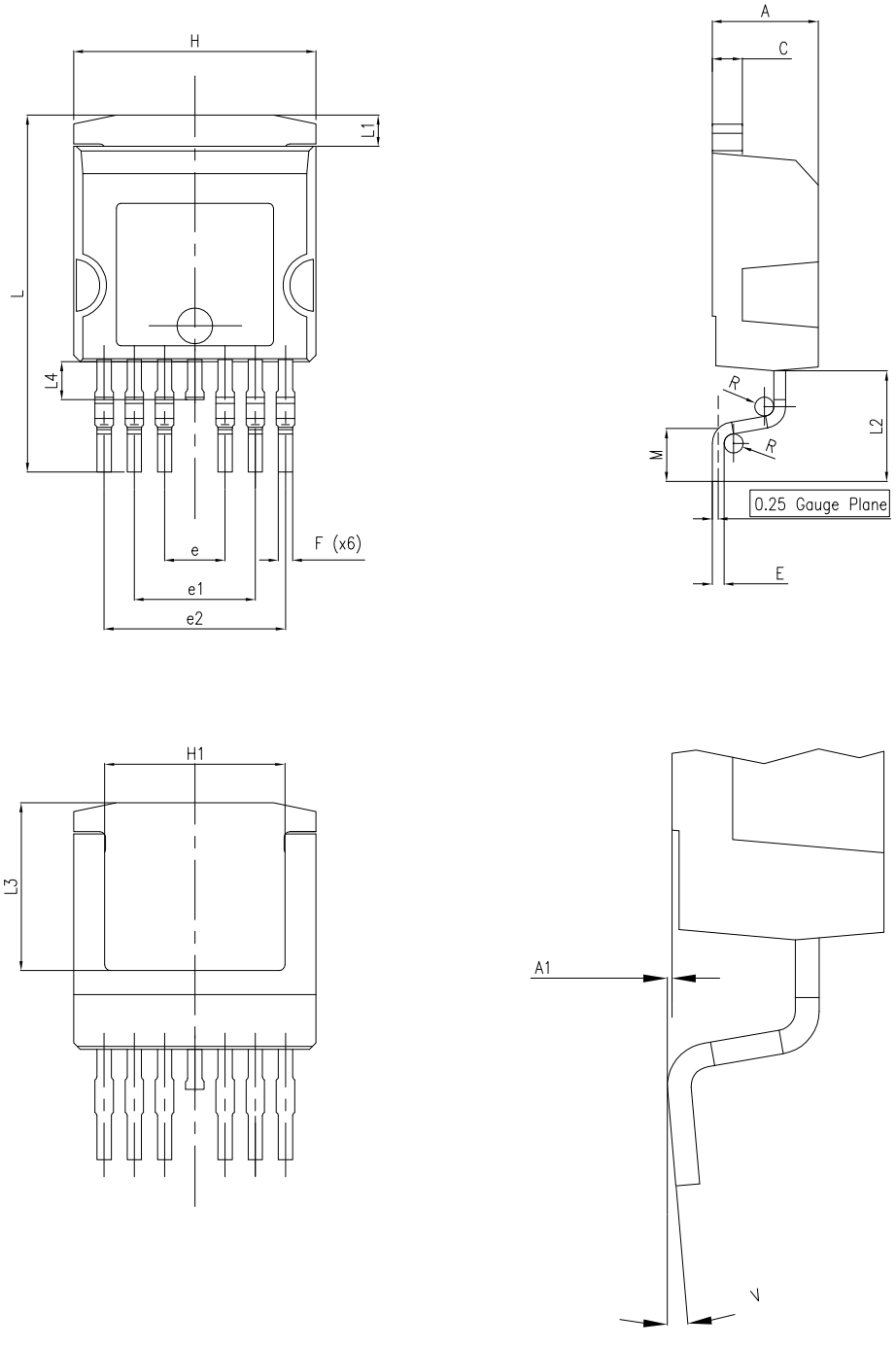


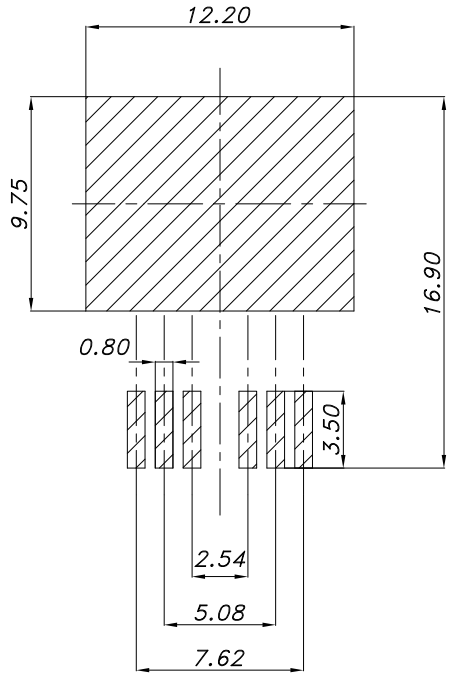
Table 8. **H²PAK-6 package mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.70
A1	0.03		0.20

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Dim.	mm		
	Min.	Typ.	Max.
C	1.17		1.37
e	2.34	2.54	2.74
e1	4.88		5.28
e2	7.42		7.82
E	0.45		0.60
F	0.50		0.70
H	10.00		10.40
H1	7.40		7.80
L	14.75		15.25
L1	1.27		1.40
L2	4.35		4.95
L3	6.85		7.25
L4	1.50		1.75
M	1.90		2.50
R	0.20		0.60
V	0°		8°

Figure 21. H²PAK-6 recommended footprint



8159693_footprint_Rev_9

Note: Dimensions are in mm.

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4.3 Packing information

Figure 22. **Tape outline**

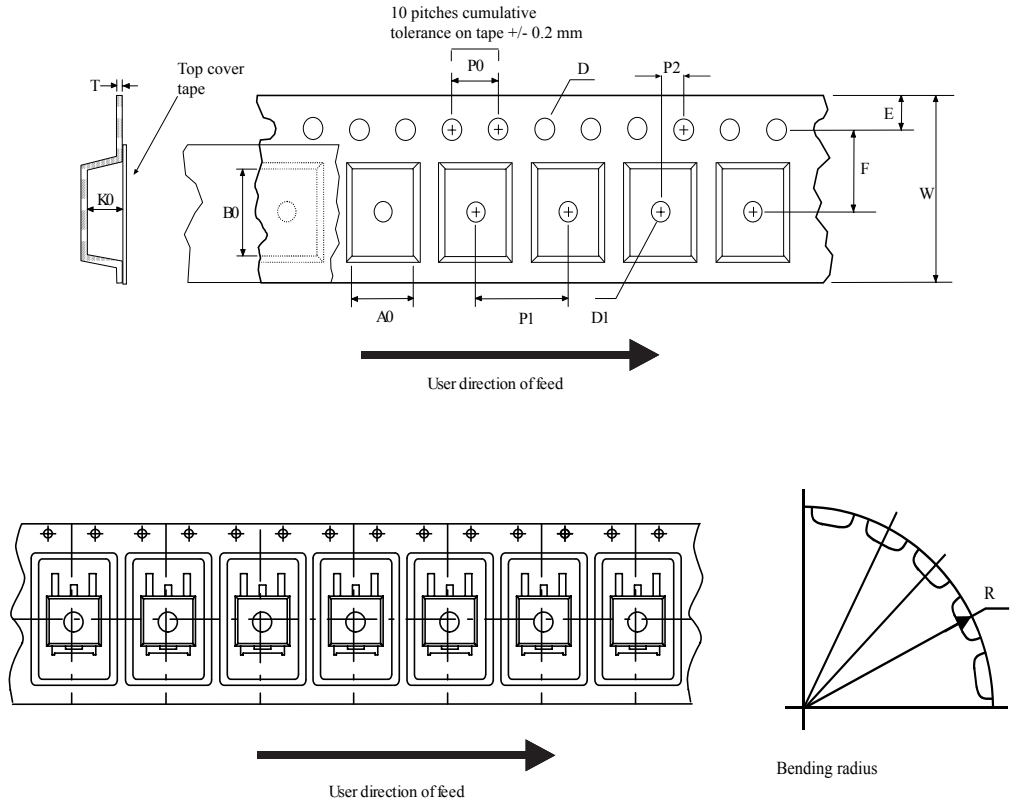
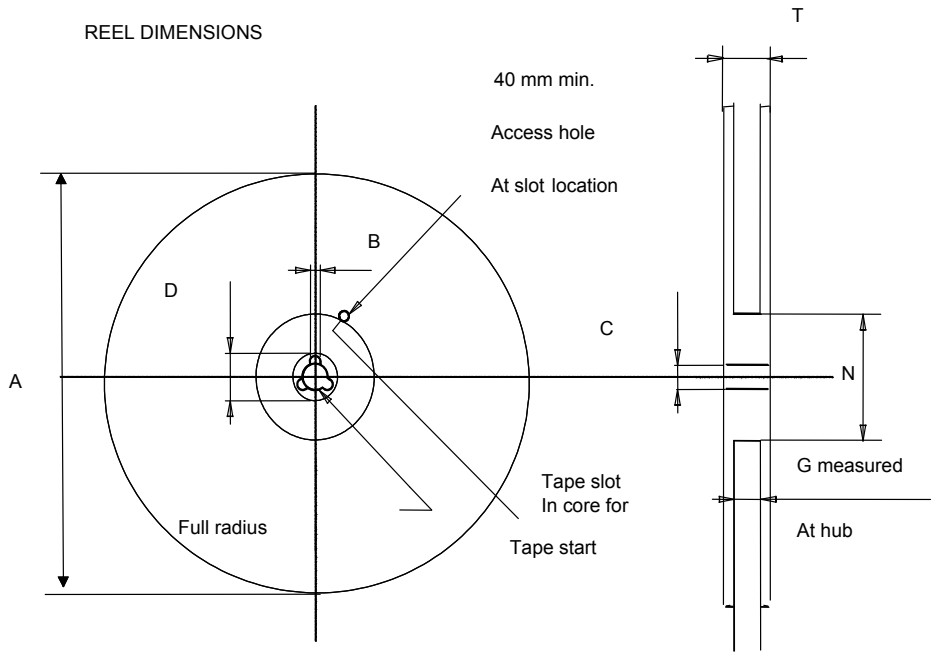


Figure 23. **Reel outline**



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Table 9. Tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
T	0.30	0.40			
W	23.7	24.3			

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Revision history

Table 10. **Document revision history**

Date	Version	Changes
02-Aug-2013	1	Initial release.
03-Sep-2013	2	– Modified: *Table 1*, RDS(on) typical value in *Table 4* – Minor text changes
27-May-2014	3	– Modified: title and *Features* in cover page – Updated: *Section 4: Package mechanical data* – Minor text changes
12-Sep-2014	4	– Modified: title, features and description in cover page.
03-May-2021	5	Updated *Table 1. Absolute maximum ratings*. Minor text changes.
28-Mar-2025	6	Updated Table 9. Tape and reel mechanical data.

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2 **Electrical characteristics** 3
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